

1024Kx8 Nonvolatile SRAM

Features

- Data retention in the absence of power
- Automatic write-protection during power-up/power-down cycles
- Conventional SRAM operation; unlimited write cycles
- ► 10-year minimum data retention in absence of power
- Battery internally isolated until power is applied

General Description

The CMOS bq4016 is a nonvolatile 8,388,608-bit static RAM organized as 1,048,576 words by 8 bits. The integral control circuitry and lithium energy source provide reliable nonvolatility coupled with the unlimited write cycles of standard SRAM.

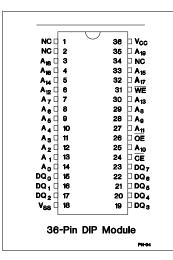
The control circuitry constantly monitors the single 5V supply for an out-of-tolerance condition. When V_{CC} falls out of tolerance, the SRAM is unconditionally write-protected to prevent an inadvertent write operation.

At this time the integral energy source is switched on to sustain the memory until after V_{CC} returns valid.

The bq4016 uses extremely low standby current CMOS SRAMs, coupled with a small lithium coin cell to provide nonvolatility without long write-cycle times and the writecycle limitations associated with EEPROM.

The bq4016 has the same interface as industry-standard SRAMs and requires no external circuitry.

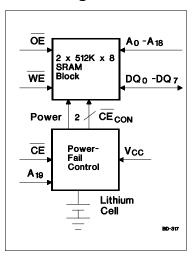
Pin Connections



A0-A19 Address inputs DQ₀–DQ₇ Data input/output CE Chip enable input OE Output enable input WE Write enable input VCC +5 volt supply input Ground Vss NC No connect

Pin Names

Block Diagram



Selection Guide

Part Number	Maximum Access Time (ns)	Negative Supply Tolerance	Part Number	Maximum Access Time (ns)	Negative Supply Tolerance
bq4016MC -70	70	-5%	bq4016YMC -70	70	-10%

Functional Description

When power is valid, the bq4016 operates as a standard CMOS SRAM. During power-down and power-up cycles, the bq4016 acts as a nonvolatile memory, automatically protecting and preserving the memory contents.

Power-down/power-up control circuitry constantly monitors the V_{CC} supply for a power-fail-detect threshold V_{PFD}. The bq4016 monitors for V_{PFD} = 4.62V typical for use in systems with 5% supply tolerance. The bq4016Y monitors for V_{PFD} = 4.37V typical for use in systems with 10% supply tolerance.

When V_{CC} falls below the V_{PFD} threshold, the SRAM automatically write-protects the data. All outputs become high impedance, and all inputs are treated as "don't care." If a valid access is in process at the time of power-fail detection, the memory cycle continues to completion. If the memory cycle fails to terminate within time t_{WPT}, write-protection takes place.

As V_{CC} falls past V_{PFD} and approaches 3V, the control circuitry switches to the internal lithium backup supply, which provides data retention until valid V_{CC} is applied.

When V_{CC} returns to a level above the internal backup cell voltage, the supply is switched back to V_{CC} . After V_{CC} ramps above the V_{PFD} threshold, write-protection continues for a time t_{CER} (120ms maximum) to allow for processor stabilization. Normal memory operation may resume after this time.

The internal coin cells used by the bq4016 have an extremely long shelf life. The bq4016 provides data retention for more than 10 years in the absence of system power.

As shipped from Benchmarq, the integral lithium cells are electrically isolated from the memory. (Self-discharge in this condition is approximately 0.5% per year.) Following the first application of V_{CC}, this isolation is broken, and the lithium backup provides data retention on subsequent power-downs.

Truth Table

Mode	CE	WE	OE	I/O Operation	Power
Not selected	Н	Х	Х	High Z	Standby
Output disable	L	Н	Н	High Z	Active
Read	L	Н	L	D _{OUT}	Active
Write	L	L	Х	D _{IN}	Active

Absolute Maximum Ratings

Symbol	Parameter	Value	Unit	Conditions
Vcc	DC voltage applied on V_{CC} relative to V_{SS}	-0.3 to 7.0	V	
VT	DC voltage applied on any pin excluding V_{CC} relative to V_{SS}	-0.3 to 7.0	V	$V_T \leq V_{CC} + 0.3$
TOPR	Operating temperature	0 to +70	°C	
T _{STG}	Storage temperature	-40 to +70	°C	
T _{BIAS}	Temperature under bias	-10 to +70	°C	
TSOLDER	Soldering temperature	+260	°C	For 10 seconds

Note: Permanent device damage may occur if **Absolute Maximum Ratings** are exceeded. Functional operation should be limited to the Recommended DC Operating Conditions detailed in this data sheet. Exposure to conditions beyond the operational limits for extended periods of time may affect device reliability.

Recommended DC Operating	Conditions (TA = 0 to 70°C)
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Symbol	Parameter	Minimum	Typical	Maximum	Unit	Notes
	Supply voltage	4.5	5.0	5.5	V	bq4016Y
Vcc		4.75	5.0	5.5	v	bq4016
Vss	Supply voltage	0	0	0	v	
VIL	Input low voltage	-0.3	-	0.8	V	
VIH	Input high voltage	2.2	-	V _{CC} + 0.3	v	

Note: Typical values indicate operation at $T_A = 25^{\circ}C$.

Symbol	Parameter	Minimum	Typical	Maximum	Unit	Conditions/Notes
I _{LI}	Input leakage current	-	-	± 2	μA	V_{IN} = V_{SS} to V_{CC}
ILO	Output leakage current	-	-	± 2	μΑ	$\overline{\underline{CE}} = V_{IH} \text{ or } \overline{OE} = V_{IH} \text{ or} \\ \overline{WE} = V_{IL}$
VOH	Output high voltage	2.4	-	-	V	I _{OH} = -1.0 mA
Vol	Output low voltage	-	-	0.4	V	$I_{OL} = 2.1 \text{ mA}$
I _{SB1}	Standby supply current	-	5	12	mA	$\overline{CE} = V_{IH}$
I _{SB2}	Standby supply current	-	2.5	5	mA	$\label{eq:Vindex} \begin{split} & \frac{0V \leq V_{IN} \leq 0.2V, \\ & \overline{CE} \geq V_{CC} \text{ - } 0.2V, \\ & \text{or } V_{IN} \geq V_{CC} \text{ - } 0.2 \end{split}$
I _{CC}	Operating supply current	-	75	115	mA	$\label{eq:min_cycle} \begin{array}{l} \underline{Min.\ cycle,\ duty\ =\ 100\%,}\\ \overline{CE}\ =\ V_{IL}\ ,I_{I/O}\ =\ 0mA,\\ A19\ <\ V_{IL}\ or\ A19\ >\ V_{IH}, \end{array}$
VPFD	Power-fail-detect voltage	4.55	4.62	4.75	V	bq4016
V PFD	rower-fail-detect voltage	4.30	4.37	4.50	V	bq4016Y
Vso	Supply switch-over voltage	-	3	-	V	

DC Electrical Characteristics (T_A = 0 to 70°C, V_{CCmin} \leq V_{CC} \leq V_{CCmax})

Note: Typical values indicate operation at $T_A = 25^{\circ}C$, $V_{CC} = 5V$.

Capacitance ($T_A = 25^{\circ}C$, F = 1MHz, $V_{CC} = 5.0V$)

Symbol	Parameter	Minimum	Typical	Maximum	Unit	Conditions
C _{I/O}	Input/output capacitance	-	-	20	pF	Output voltage = 0V
C _{IN}	Input capacitance	-	-	20	pF	Input voltage = 0V

Note: These parameters are sampled and not 100% tested.

AC Test Conditions

Parameter	Test Conditions		
Input pulse levels	0V to 3.0V		
Input rise and fall times	5 ns		
Input and output timing reference levels	1.5 V (unless otherwise specified)		

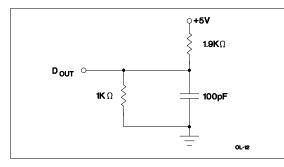


Figure 1. Output Load A

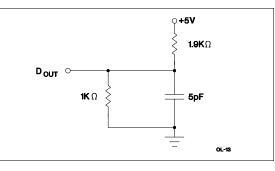
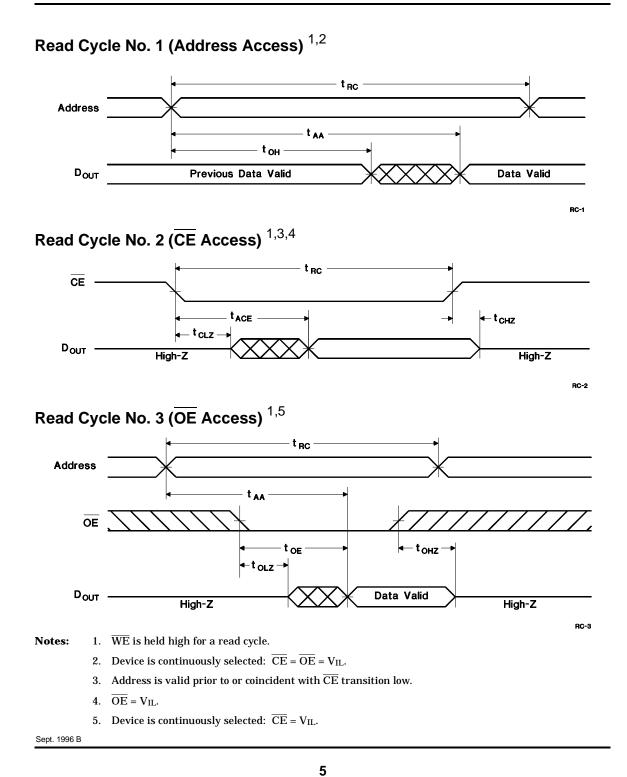


Figure 2. Output Load B

Read Cycle (T_A = 0 to 70°C, V_{CCmin} \leq V_{CC} \leq V_{CCmax})

		-	-70		-70			
Symbol	Parameter	Min.	Max.	Unit	Conditions			
trc	Read cycle time	70	-	ns				
t _{AA}	Address access time	-	70	ns	Output load A			
tACE	Chip enable access time	-	70	ns	Output load A			
toE	Output enable to output valid	-	35	ns	Output load A			
tclz	Chip enable to output in low Z	5	-	ns	Output load B			
tolz	Output enable to output in low Z	5	-	ns	Output load B			
t _{CHZ}	Chip disable to output in high Z	0	25	ns	Output load B			
tonz	Output disable to output in high Z	0	25	ns	Output load B			
tон	Output hold from address change	10	-	ns	Output load A			



		-70				
Symbol	Parameter	Min.	Max.	Units	Conditions/Notes	
twc	Write cycle time	70	-	ns		
t _{CW}	Chip enable to end of write	65	-	ns	(1)	
taw	Address valid to end of write	65	-	ns	(1)	
t _{AS}	Address setup time	0	-	ns	Measured from address valid to beginning of write. (2)	
t _{WP}	Write pulse width	55	-	ns	Measured from beginning of write to end of write. (1)	
t _{WR1}	Write recovery time (write cycle 1)	5	-	ns	Measured from $\overline{\rm WE}$ going high to end of write cycle. (3)	
t _{WR2}	Write recovery time (write cycle 2)	15	-	ns	Measured from \overline{CE} going high to end of write cycle. (3)	
t _{DW}	Data valid to end of write	30	-	ns	Measured to first lo <u>w-to-high</u> transition of either CE or WE.	
t _{DH1}	Data hold time (write cycle 1)	0	-	ns	Measured from $\overline{\rm WE}$ going high to end of write cycle. (4)	
t _{DH2}	Data hold time (write cycle 2)	10	-	ns	Measured from \overline{CE} going high to end of write cycle. (4)	
twz	Write enabled to output in high Z	0	25	ns	I/O pins are in output state. (5)	
tow	Output active from end of write	5	-	ns	I/O pins are in output state. (5)	

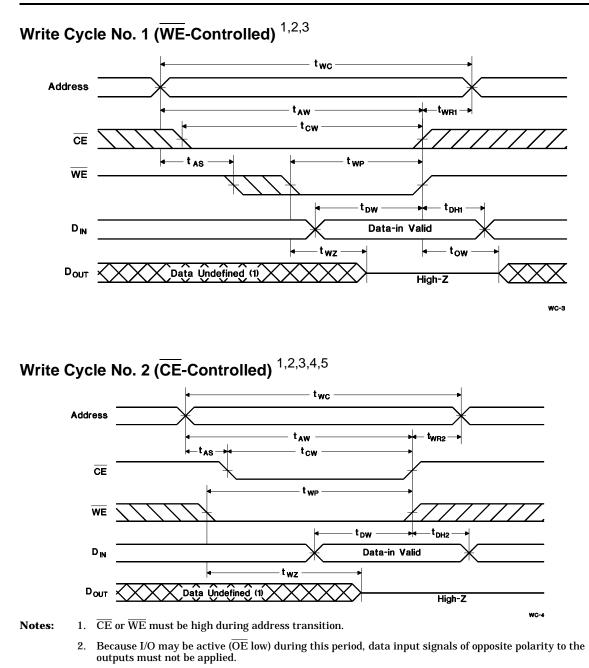
Write Cycle (TA = 0 to 70°C, VCCmin \leq VCC \leq VCCmax)

Notes:

1. A write ends at the earlier transition of \overline{CE} going high and \overline{WE} going high.

2. A write occurs during the overlap of a low \overline{CE} and a low \overline{WE} . A write begins at the later transition of \overline{CE} going low and \overline{WE} going low.

- 3. Either t_{WR1} or t_{WR2} must be met.
- 4. Either t_{DH1} or t_{DH2} must be met.
- 5. If $\overline{\text{CE}}$ goes low simultaneously with $\overline{\text{WE}}$ going low or after $\overline{\text{WE}}$ going low, the outputs remain in high-impedance state.



- 3. If \overline{OE} is high, the I/O pins remain in a state of high impedance.
- 4. Either t_{WR1} or t_{WR2} must be met.
- 5. Either t_{DH1} or t_{DH2} must be met.

	Symbol	Parameter	Minimum	Typical	Maximum	

Power-D	own/Power-Up	Cycle (TA	= 0 to 70°C)

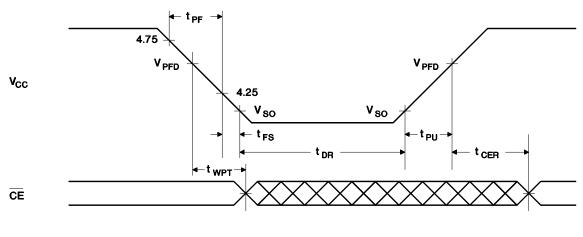
Symbol	Parameter	Minimum	Typical	Maximum	Unit	Conditions
tpf	V _{CC} slew, 4.75 to 4.25 V	300	-	-	μs	
t _{FS}	V_{CC} slew, 4.25 to V_{SO}	10	-	-	μs	
tpu	V _{CC} slew, V _{SO} to V _{PFD} (max.)	0	-	-	μs	
t _{CER}	Chip enable recovery time	40	80	120	ms	Time during which SRAM is write-protected after V _{CC} passes V _{FPD} on power-up.
tdr	Data-retention time in absence of V_{CC}	10	-	-	years	$T_{\rm A} = 25^{\circ}C.$ (2)
t _{WPT}	Write-protect time	40	100	150	μs	$\begin{array}{l} Delay \ after \ V_{CC} \ slews \\ down \ past \ V_{PFD} \ before \\ SRAM \ is \ write-protected. \end{array}$

Notes: 1. Typical values indicate operation at $T_A = 25^{\circ}C$, $V_{CC} = 5V$.

> 2. Batteries are disconnected from circuit until after V_{CC} is applied for the first time. t_{DR} is the accumulated time in absence of power beginning when power is first applied to the device.

Caution: Negative undershoots below the absolute maximum rating of -0.3V in battery-backup mode may affect data integrity.

Power-Down/Power-Up Timing



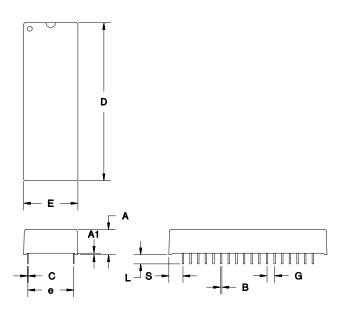
PD-B

Data Sheet Revision History

Change No.	Page No.	Description
1	All	Changed from "Preliminary" to "Final" data sheet
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Notes: Change 1 = Sept 1996 B changes from June 1995.

MC: 36-Pin C-Type Module

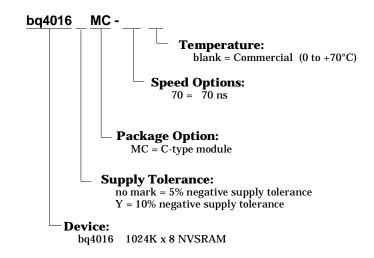


36-Pin MC (C-Type Module)

Minimum	Maximum
0.365	0.375
0.015	-
0.017	0.023
0.008	0.013
2.070	2.100
0.710	0.740
0.590	0.630
0.090	0.110
0.120	0.150
0.175	0.210
	0.365 0.015 0.017 0.008 2.070 0.710 0.590 0.090 0.120

All dimensions are in inches.

Ordering Information





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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
BQ4016MC-70	NRND	DIP MODULE	MC	36	10	Pb-Free (RoHS)	Call TI	N / A for Pkg Type	Add to cart
BQ4016YMC-70	NRND	DIP MODULE	MC	36	10	Pb-Free (RoHS)	Call TI	N / A for Pkg Type	Add to cart

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

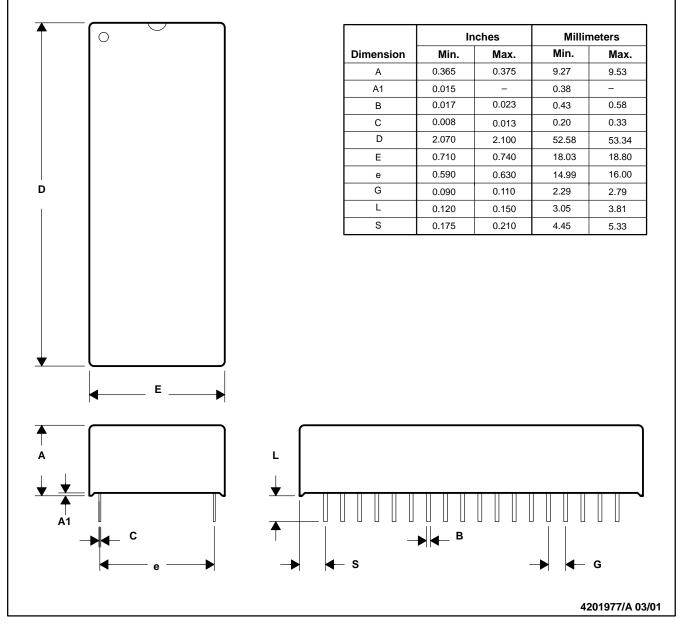
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MECHANICAL DATA

MPDI063 - MAY 2001

PLASTIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (mm). B. This drawing is subject to change without notice.

MC (R-PDIP-T36)



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